Theoretical Analysis of a Three-Phase Bidirectional Isolated DC-DC Converter Using Phase-Shifted Modulation

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Article Info	ABSTRACT
Article history:	A three-phase bidirectional isolated dc-dc converter consists of two six-pulse two-level active converters that enable bidirectional power flow by introducing a lag phase-shift angle of one converter with respect to the other converter. This paper explains the operating modes of a three-phase bidirectional isolated dc-dc converter in detail, taking into account the transfer of energy between the dc voltage sources and high-frequency ac inductances in the three-phase bidirectional isolated dc-dc converter. The power flow of the dc-dc converter is also examined based on the operating modes
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1. INTRODUCTION

DC-DC converters are classified into single- or three-phase circuit configurations. From singlephase configurations, these converters are classified into full- or half-bridge. Half-bridge circuits need only half the number of power electronic switches required in full-bridge. Authors of [1] carried out simulation on this topology and discovered that it has major advantages such as reduced switching losses and low electromagnetic interference. The three-phase dc-dc converter typically consist of six-pulse two-level or neutral-point-clamp converters. The converters are also differentiated by the direction of power flow unidirectional and bidirectional. Unidirectional converters only allow single direction of power flow, whereas bidirectional converters enable energy to transfer between its input and output. Bidirectional converters are assorted into isolated and non-isolated topology. The isolated type converters provide a galvanic isolation and voltage matching at the DAB [2] and [3]. In the isolated bidirectional converter, both sides of the converter employ active bridges to form a dual active bridge (DAB). These DC-DC converters are being widely used in many areas such as in solid-state transformers for the distribution systems, renewable energy systems, battery energy storage systems for grid and electric vehicle [4]-[12]. Non-isolated topologies have aso been considered for grid-interconnection of dc distribution systems [13]-[15].

The single-phase dual active bridge (SPDAB) has gained popularity due to the improvements in 5th generation trench-gate Insulated Gate Bipolar Transistors (IGBTs) technology that results in a high converter efficiency of up to 97% [2]. Its power flow is controlled by applying various types of modulation techniques. The common techniques include the phase-shift, triangular and trapezoidal modulation techniques. The efficiency of a converter at different power transfer range depend on switching techniques at the power

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Figure 1. A three-phase dual active bridge.

electronic switches. The phase-shifted modulation has an advantage such that zero-voltage switching (ZVS). However, there is a limitation, whereby this technique produces high circulating current when operate far from the dc-dc converter's nominal operating point [10]. Triangular modulation is being applied on a SPDAB to ensure ZVS at all switches. It is also suitable for the use in applications that has high voltage differences between the input and output of the converters. Trapezoidal modulation is best being used in applications which has low voltage differences between input and the output [10], [11], and [16]. It has more frequent hard-switching turn-off processes as compared to triangular modulation. Another method is to combine all three techniques mentioned above, also known as optimal modulation scheme. This scheme is being used for the yield of higher efficiency on the SPDAB. This hyrbrid modulation strategy could also be applied on a three-phase bidirectional isolated dc-dc converter (TPDAB) [17].

The TPDAB is more suitable for a high-power density application, as it has several advantages including the ability of operation at wide range of voltage and power, low turn-off peak currents in the power switches, higher efficiency, and reduced filter volume and costs [9]. They are employed for high-power applications energy storage systems that are grid connected or employed in electric vehicles [17] and [18]. Eventhough the hybrid modulation strategy can improve the efficiency of the TPDAB over a wide range of voltage level and power transfer, the mouldation strategy need high computation power. In addition, the challenge of the converter is in the implementation of a three-phase high-frequency transformer. Nevertheless, the converter is gaining interest for application that requires high-power density.

This paper presents the operation modes of the TPDAB based on phase-shift modulation. Although the authors in [9] presented the topology and discussed the power transfer modes of the TPDAB, this paper presents the mode-by-mode analysis for the first half of the TPDAB operations by considering the energy transfer between the dc voltage sources and the high-frequency ac inductances. This analysis is intended to be an initial reference and to aid students and researchers to understand the operating principles of the TPDAB. Finally, this paper also discusses the power flow analysis of the TPDAB.

2. CIRCUIT CONFIGURATION OF A TPDAB

Figure 1a shows the circuit configuration of a TPDAB. It consists of bridge 1 and bridge 2. Each of the bridges are connected to a dc voltage source, where V_1 represents the voltage source at bridge 1, and V_2 is the voltage source at bridge 2. At each of the bridges, there are six IGBTs as the power semiconductor switches, with a freewheeling diode and a snubber capacitor connected in parallel to each switch. The freewheeling diodes are being used in the implementation of a TPDAB so that it could provide a path to transfer the current when IGBTs are gated to turn off, and the snubber capacitors are connected to achieve ZVS operation. A three-phase transformer with high-frequency operation is employed to provide galvanic isolation while increasing the power density. The transformer turn ratio, d is N_1 : N_2 , where N_1 is the number of turns on bridge 1 side and N_2 is the number of turns on bridge 2 side. The high frequency applied to this transformer is usually above 20 kHz. It is designed to prevent audible noises, and to reduce the magnetic component size of the converter. At bridge 1, S_{11} to S_{16} are IGBTs, and D_{11} to D_{16} are freewheeling diodes. Since the circuit is symmetrical, bridge 2 has similar components and topology, where, S_{21} to S_{26} are IGBTs, and D_{21} to D_{26} are freewheeling diodes. The first subscript number represents the bridge number, either 1 or 2, whereas the second subscript number represents the switch number, from 1 to 6.



Figure 2. Gating signal control of a TPDAB based on phase-shift modulation. (a) Bridge 1. (b) Bridge 2.

Figure 1b shows the circuit configuration of the TPDAB referred to the bridge-1-side. All components remained the same as in Figure 1a. However, the dc voltage source at bridge 2 is now referred to bridge-1-side and it is denoted as V_1 ' (= dV_1). The three-phase transformer is now represented as three individual transformer leakage reactance at each of the phases. The three-phase transformer reactances can be represented as leakage inductors as derived in [3] and [9]. It is seen that through transformation of the simplified single equivalent circuit, the transformer reactance, L can be reduced to $L_{\sigma} = d^2 L_{sl} + L_{pl}$, where L_{sl} and L_{pl} are the primary and secondary leakage inductances, with the assumptions of $i_{as} = i_{ap} = i(\phi)$ for phase A. The per phase leakage inductance of the transformer is used as the power transfer element as described in Section 4.

3. ANALYSIS OF THE TPDAB OPERATING MODES

Table 1 presents the switching modes for the TPDAB based on phase-shift modulation [9]. Typically, there are twelve modes of operation. However, due to the symmetry of the waveform, the analysis is carried out for the first six of the operating modes (0 to π). In the analysis, power is assumed to flow from bridge 1 to bridge 2, with the phase-shift angle ϕ being positive.

Figure 2 shows the gating signal control of the IGBTs on both bridge 1 and bridge 2 deduced from Table 1. Each of the switches conduct for 180° per cycle. When the power flow is zero, T_{11} is turned on at the same time as T_{21} . T_{12} and T_{22} remains off. To ensure power to flow from bridge 1 to bridge 2, a lag phase-shift angle, ϕ is introduced in bridge 2. The relationship of average power transfer with the phase-shift angle is explained in Section 4.

Referring to Figure 1, the difference between the voltages in bridge 1 and bridge 2 determines the rate of change of three-phase transformer currents, i_a , i_b , i_c , through leakage inductors, L_a , L_b , and L_c . A balanced TPDAB circuit is assumed, where $i_a + i_b + i_c = 0$. Figure 4 shows the idealized operating waveforms of the TPDAB on phase A. These waveforms show the ac voltage waveform for bridge 1 and bridge 2, and the ac current of bridge 1. It is important to take note that there is a 120° phase-shift between phases A, B, and C. The phase current i_a in Figure 4 demonstrates the charging and discharging mode of inductors L_a , L_b and L_c . The change in voltage across an inductor is proportional to the rate of change of current in the inductor. The inductor stores and supplies energy when the product of the change in voltage and current flow in it is positive and negative, respectively. The operating mode analysis in this paper assumes the commutations of current in the snubber capacitors are instantaneous.

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3.1. Mode 1 ($\theta < \theta \le \phi$)

Figure 3a presents mode 1 operation of the TPDAB. In this mode, transistors T_{11} , T_{14} , T_{15} , and T_{22} are turned on. Energy from source V_1 and L_c is transferred to source V_1 ' and inductor L_b when the current flows through the route of T_{15} - D_{25} - D_{24} - T_{14} . Initially, inductor L_a also supplies energy to V_1 ' via the current







Figure 3. The main operating modes of the TPDAB. (a) Mode 1. (b) Mode 2. (c) Mode 3. (d) Mode 4. (e) Mode 5. (f) Mode 6.

flow route of D_{25} - D_{22} - D_{11} - T_{15} . Once the current in L_a reduces to zero, T_{11} will start to conduct current and L_a is charged from source V_1 through the current route of T_{11} - T_{22} - D_{24} - T_{14} .

3.2. Mode 2 ($\phi < \theta \le \pi/3$)

Figure 3b shows mode 2 operation of the TPDAB. During the mode, transistors, T_{11} , T_{14} , and T_{15} are turned on. Energy is transferred from Source V_1 to V_1 ' via the route of T_{11} - D_{21} - D_{24} - T_{14} and T_{15} - D_{25} - D_{24} - T_{14} . The rate of change of current in the inductors are constant. Ideally, no energy is stored in or supplied by the inductors.

3.3. Mode 3 ($\pi/3 < \theta \le \phi + \pi/3$)

Figure 3c presents mode 3 operation of the TPDAB. In this mode, transistors T_{11} , T_{14} , T_{16} , and T_{25} are turned on. Energy from source V_1 and L_{b} are transferred to source V_1 ' and inductor L_a when the

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current flows through the route of T_{11} - D_{21} - D_{24} - T_{14} . Initially, inductor L_c supplies energy to V_1 ' via the current flow route of T_{11} - D_{21} - D_{24} - T_{14} . Once the current in L_c reduces to zero, the direction of current in phase C changes from positive to negative. Inductor L_c is charged from source V_1 through the current route of T_{11} - D_{21} - T_{25} - T_{16} .

3.4. Mode 4 ($\phi + \pi/3 < \theta \le 2\pi/3$)

Figure 3d shows mode 4 operation of the TPDAB. During the mode, transistors, T_{11} , T_{14} , and T_{16} are turned on. Energy is transferred from Source V_1 to V_1 ' via the route of T_{11} - D_{21} - D_{24} - T_{14} and T_{11} - D_{21} - D_{26} - T_{16} . The rate of change of current in the inductors are constant. Ideally, no energy is stored in or supplied by the inductors.

3.5. Mode 5 $(2\pi/3 < \theta \le \phi + 2\pi/3)$

Figure 3e illustrates mode 5 operation of the TPDAB. In this mode, transistors T_{11} , T_{13} , T_{16} , and T_{24} are turned on. Energy from source V_1 and L_a is transferred to source V_1 ' and inductor L_c when the current flows through the route of T_{11} - D_{21} - D_{26} - T_{16} . Initially, inductor L_b also supplies energy to V_1 ' via the current flow route of D_{21} - D_{24} - D_{13} - T_{11} . Once the current in L_b reduces to zero, T_{13} will start to conduct current and L_b is charged from source V_1 through the current route of T_{13} - T_{24} - D_{26} - T_{16} .

3.6. Mode 6 ($\phi + 2\pi/3 < \theta \le \pi$)

Figure 3f shows mode 6 operation of the TPDAB. During the mode, transistors, T_{11} , T_{13} , and T_{16} are turned on. Energy is transferred from Source V_1 to V_1 ' via the route of T_{11} - D_{21} - D_{26} - T_{16} and T_{13} - D_{23} - D_{26} - T_{16} . The rate of change of current in the inductors are constant. Ideally, no energy is stored in or supplied by the inductors.

4. POWER FLOW ANALYSIS

Equation (1) shows the equivalent leakage inductance of the TPDAB, where $X_{L,eq}$ is the overall leakage reactance at the ac side of bridge 1. Whereas, individual leakage reactance for phases A, B, and C are represented by X_L . For every operating mode, since current in two out of three phase legs flow in the same direction, thus the reactances are parallel to each other, yielding the formula $X_L/2$.

$$X_{L,eq} = X_L + \frac{X_L}{2} = \frac{3X_L}{2}$$
(1)

By applying voltage divider rule, the voltages across all three phases during mode 1 operation ($0 < \theta \le \phi$) are obtained as shown in Equation (2) and (3):

$$v_{ap} = v_{cp} = \frac{X_L}{2} / \frac{X_L}{3X_L} \times V_1 = \frac{X_L}{2} \times \frac{2V_1}{3X_L} = \frac{V_1}{3}$$
(2)

$$v_{bp} = \frac{X_L}{3X_L} \times -V_1 = X_L \times -\frac{2V_1}{3X_L} = -\frac{2}{3}V_1$$
(3)

The current flowing through the inductor at phase A in mode 1 operation can be defined using piecewiselinear equations:

$$i_{ap} = i_{as} = i(\theta) \tag{4}$$

$$i(\theta) = i(0) + \frac{V_1 + dV_2}{3\omega L_a}(\theta)$$
(5)

where V_1 is the bridge 1 dc voltage, ω is the angular frequency, L_a is the transformer leakage inductance of phase A, d is the transformer turns ratio, and ϕ is the phase-shift angle.

By applying voltage divider rule, the voltages across all three phases during mode 2 operation ($\phi < \theta \le \pi/3$) are:

$$v_{ap} = v_{cp} = \frac{X_L}{2} / \frac{X_L}{2} \times V_1 = \frac{X_L}{2} \times \frac{2V_1}{3X_L} = \frac{V_1}{3}$$
(6)

$$v_{bp} = \frac{X_L}{\frac{3X_L}{2}} \times -V_1 = X_L \times -\frac{2V_1}{3X_L} = -\frac{2}{3}V_1$$
⁽⁷⁾

The current flowing through the inductor at phase A in mode 2 operation can be defined using piecewiselinear equations, also by referring to Equation (4), the equation is:

$$i(\theta) = i(\phi) + \frac{V_1 - dV_2}{3\omega L_a}(\theta - \phi)$$
(8)

By applying voltage divider rule, the voltages across all three phases during mode 3 operation ($\pi/3 < \theta \le \phi + \pi/3$) are:

$$v_{bp} = v_{cp} = \frac{X_L}{2} / \frac{X_L}{2} \times -V_1 = \frac{X_L}{2} \times -\frac{2V_1}{3X_L} = -\frac{V_1}{3}$$
(9)

$$v_{ap} = \frac{X_L}{\frac{3X_L}{2}} \times V_1 = X_L \times \frac{2V_1}{3X_L} = \frac{2}{3}V_1$$
(10)



Figure 4: Idealized operating waveforms of TPDAB on phase A.

(a) Bridge 1 ac voltage; (b) Bridge 2 ac voltage; (c) Bridge 1 ac current. The current flowing through the inductor at phase A in mode 3 operation can be defined using piecewiselinear equations, also by referring to Equation (4), the equation is:

$$i(\theta) = i\left(\frac{\pi}{3}\right) + \frac{2V_1 - dV_2}{3\omega L_a} \left(\theta - \frac{\pi}{3}\right) \tag{11}$$

$$v_{bp} = v_{cp} = \frac{X_L}{2} / \frac{X_L}{2X_L} \times -V_1 = \frac{X_L}{2} \times -\frac{2V_1}{3X_L} = -\frac{V_1}{3}$$
(12)

$$v_{ap} = \frac{X_L}{\frac{3X_L}{2}} \times V_1 = X_L \times \frac{2V_1}{3X_L} = \frac{2}{3}V_1$$
(13)

The current flowing through the inductor at phase A in mode 4 operation can be defined using piecewiselinear equations, also by referring to Equation (4), the equation is:

$$i(\theta) = i\left(\phi + \frac{\pi}{3}\right) + \frac{2V_1 - 2dV_2}{3\omega L_a}\left(\theta - \phi - \frac{\pi}{3}\right) \tag{14}$$

By applying voltage divider rule, the voltages across all three phases during mode 5 operation $(2\pi/3 < \theta \le \phi + 2\pi/3)$ are:

$$v_{ap} = v_{bp} = \frac{X_L}{2} / \frac{X_L}{2} \times V_1 = \frac{X_L}{2} \times \frac{2V_1}{3X_L} = \frac{V_1}{3}$$
(15)

$$v_{cp} = \frac{X_L}{\frac{3X_L}{2}} \times -V_1 = X_L \times -\frac{2V_1}{3X_L} = -\frac{2}{3}V_1$$
(16)

The current flowing through the inductor at phase A in mode 5 operation can be defined using piecewiselinear equations, also by referring to Equation (4), the equation is:

$$i(\theta) = i\left(\frac{2\pi}{3}\right) + \frac{V_1 - 2dV_2}{3\omega L_a} \left(\theta - \frac{2\pi}{3}\right)$$
(17)

By applying voltage divider rule, the voltages across all three phases during mode 6 operation ($\phi + 2\pi/3 < \theta \le \pi$) are:

$$v_{ap} = v_{bp} = \frac{X_L}{2} / \frac{X_L}{3X_L} \times V_1 = \frac{X_L}{2} \times \frac{2V_1}{3X_L} = \frac{V_1}{3}$$
(18)

$$v_{cp} = \frac{X_L}{\frac{3X_L}{2}} \times -V_1 = X_L \times -\frac{2V_1}{3X_L} = -\frac{2}{3}V_1$$
(19)

The current flowing through the inductor at phase A in mode 6 operation can be defined using piecewiselinear equations, also by referring to Equation (4), the equation is:

$$i(\theta) = i\left(\phi + \frac{2\pi}{3}\right) + \frac{V_1 - dV_2}{3\omega L_a}\left(\theta - \frac{2\pi}{3} - \phi\right)$$

$$\tag{20}$$

Thus, by equating Equation (5) and (20), whereby $i(0) = -i(\pi)$, and solving it, Equation (21) is obtained as shown below [9]:

$$i(0) = \frac{V_1}{2\omega L_a} \left(\frac{2\phi}{3} - \frac{5\pi}{9}\right) + \frac{dV_2}{2\omega L_a} \left(\frac{4\pi}{9} - \frac{\phi}{3}\right)$$
(21)

The dc-source current is being reconstructed by the input bridge switching function using $i(\theta)$. Thus, the average output power when $0 \le \phi \le \pi/3$ is [9]:

$$P_o = \frac{V_1^2}{\omega L} d\phi \left(\frac{2}{3} - \frac{\phi}{2\pi}\right) \tag{22}$$

For the duration of $\pi/3 \le \phi \le 2\pi/3$, the average output power is [9]:

$$P_{o} = \frac{V_{1}^{2}}{\omega L} d\left(\phi - \frac{\phi^{2}}{\pi} - \frac{\pi}{18}\right)$$
(23)

5. CONCLUSION

This paper has discussed the operation modes of the three-phase dual-active bridge (TPDAB) based on phase-shift modulation. It considers the transfer of energy between the dc voltage sources and highfrequency ac inductances in the three-phase bidirectional isolated dc-dc converter. Finally, the mathematical modesl of the transformer voltage and current are analysed, leading to the model of the average power flow in the TPDAB, that is based on first principles.

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